NPN Epitaxial Planar Silicon Transistor

2SC2814



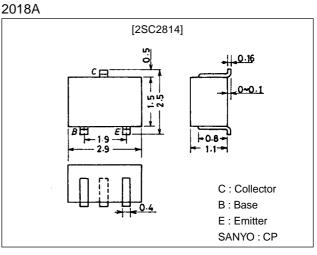
High-Friquency General-Purpose Amplifier Applications

Features

- Very small package enabiling compactness and slimness of sets.
- \cdot High f_T and small c_{re} (f_T=320MHz typ, $c_{re}{=}0.95 pF$ typ).

Package Dimensions

unit:mm



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		30	V
Collector-to-Emitter Voltage	VCEO		20	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	ΙC		30	mA
Collector Dissipation	PC		150	mW
Junction Temperature	Tj		125	°C
Storage Temperature	Tstg		-55 to +125	°C

Electrical Characteristics at Ta = 25°C

JUUUI		Ratings			Unit
Symbol	Conditions	min	typ	max	Unit
ICBO	V _{CB} =10V, I _E =0			0.1	μΑ
IEBO	$V_{EB}=4V, I_{C}=0$			0.1	μA
hFE	V _{CE} =6V, I _C =1mA	40*		270*	
fT	V _{CE} =6V, I _C =1mA	200	320		MHz
C _{re}	V _{CB} =6V, f=1MHz	0.7	0.95	1.2	pF
rbb'CC	V _{CE} =6V, I _C =1mA, f=31.9MHz		12	20	ps
NF	V _{CE} =6V, I _C =1mA, f=100MHz		3.0		dB
PG	V _{CE} =6V, I _C =1mA, f=100MHz		25		dB
	IEBO hFE fT Cre rbb'CC NF	$\label{eq:resolution} \begin{array}{ c c c c c } \hline I_{EBO} & V_{EB} = 4V, I_{C} = 0 \\ \hline h_{FE} & V_{CE} = 6V, I_{C} = 1mA \\ \hline f_T & V_{CE} = 6V, I_{C} = 1mA \\ \hline C_{re} & V_{CB} = 6V, f = 1MHz \\ \hline rbb'C_C & V_{CE} = 6V, I_{C} = 1mA, f = 31.9MHz \\ \hline NF & V_{CE} = 6V, I_{C} = 1mA, f = 100MHz \\ \hline PG & V_{CE} = 6V, I_{C} = 1mA, f = 100MHz \\ \hline \end{array}$	IEBO VEB=4V, IC=0 hFE VCE=6V, IC=1mA 40* fT VCE=6V, IC=1mA 200 Cre VCB=6V, F=1MHz 0.7 rbb'CC VCE=6V, IC=1mA, f=31.9MHz NF NF VCE=6V, IC=1mA, f=100MHz PG	IEBO VEB=4V, IC=0 hFE VCE=6V, IC=1mA 40* fT VCE=6V, IC=1mA 200 320 Cre VCB=6V, IC=1mA, f=31.9MHz 0.7 0.95 rbb'CC VCE=6V, IC=1mA, f=31.9MHz 12 NF VCE=6V, IC=1mA, f=100MHz 3.0 PG VCE=6V, IC=1mA, f=100MHz 25	IEBO VEB=4V, IC=0 0.1 hFE VCE=6V, IC=1mA 40* 270* fT VCE=6V, IC=1mA 200 320 Cre VCB=6V, IC=1mA, f=31.9MHz 0.7 0.95 1.2 rbb'CC VCE=6V, IC=1mA, f=31.9MHz 12 200 NF VCE=6V, IC=1mA, f=100MHz 3.0 3.0

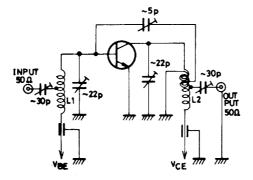
*: The 2SC2814 are classified as follows by h_{FE} at 1mA: 40 2 80 60 3 120 90 4 180 135 5 270

(Note) Marking : F h_{FE} rank : 2, 3, 4, 5

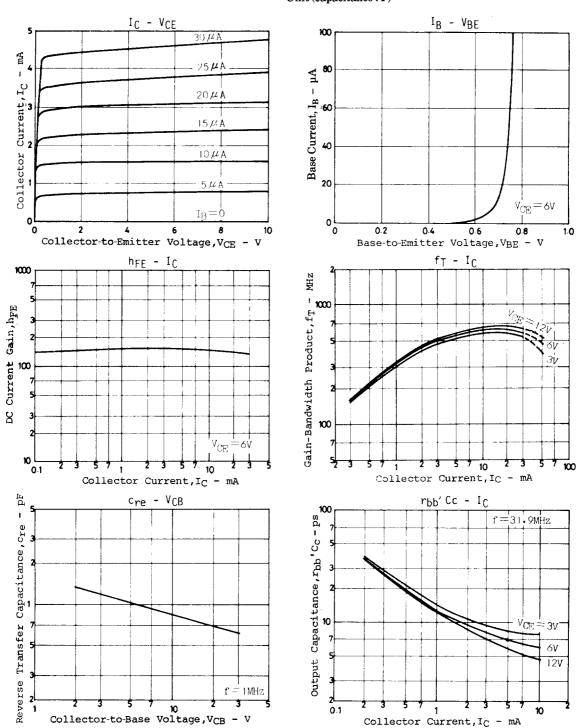
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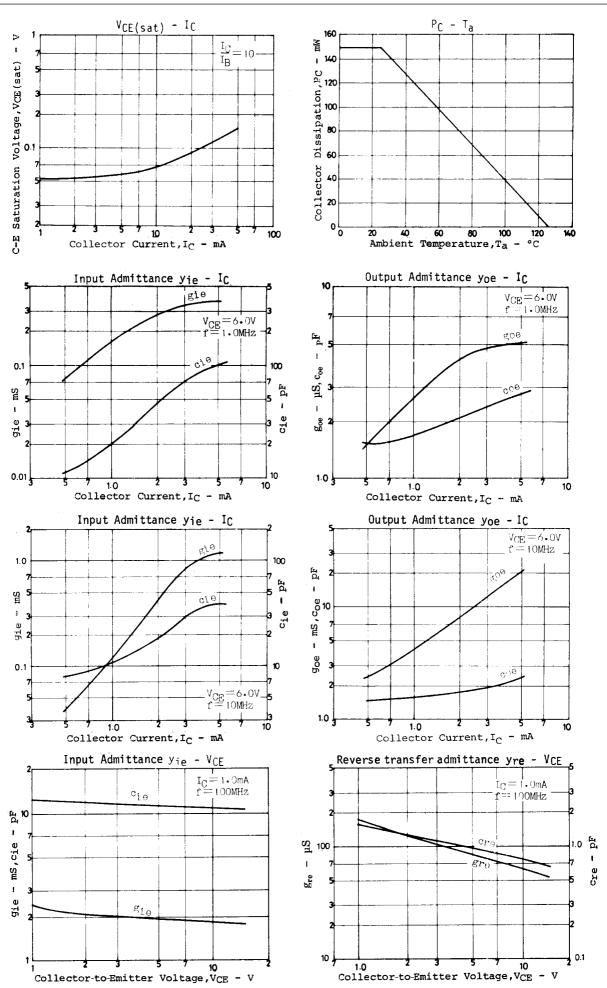


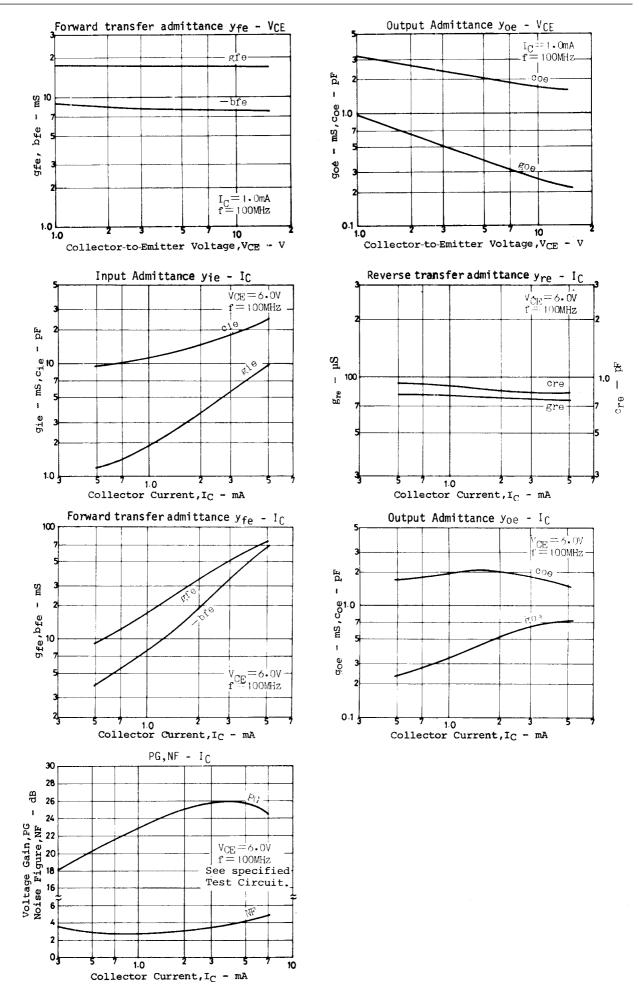


L1: lmmø plated wire 10mmø 4T, tap: 2T from $V_{\rm BE}$ side. L2: lmmø plated wire 10mmø 7T, tap: 1T from $V_{\rm CE}$ side. L3: lmmø enameled wire 10mmø 3T.



Unit (capacitance : F)





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